

Taiwan Semiconductor

### Small Signal Product

# **Bi-directional ESD Protection Diode**

#### FEATURES

- Meet IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- Designed for mounting on small surface
- Protects one Bi-directional I/O line
- Moisture sensitivity level 1
- Working Voltage : 5V, 12V, 24V
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

#### **MECHANICAL DATA**

- Case: 0503 small outline plastic package
- Terminal : Gold plated, solder per
- MIL-STD-705, method 2026 guaranteed
- High temperature soldering guaranteed : 260°C/10s
- Weight: 2 ± 0.5 mg

#### APPLICATIONS

- Cell Phone Handsets and Accessories
- Notebooks, Desktops, and Servers
- Keypads, Side Keys, USB 2.0, LCD Displays
- Portable Instrumentation
- Touch Panel



0503







PARAME	ſER	SYMBOL	VALUE	UNIT
	TESDE5V0		75	
Peak Pulse Power (tp=8/20µs waveform)	TESDE12V	P <sub>PP</sub>	25	W
	TESDE24V		47	
ESD per IEC 61000-4-2 (Air)	N/	± 15	кv	
ESD per IEC 61000-4-2 (Contact)		V <sub>ESD</sub>	± 8	KV
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

PA	RAMETER		SYMBOL	MIN	MAX	UNIT
	TESDE5V0			-	5	
Reverse Stand-Off Voltage	TESDE12V		V <sub>RWM</sub>	-	12	V
	TESDE24V			-	24	
	TESDE5V0			5.1	-	
Reverse Breakdown Voltage	TESDE12V	$I_R = 1 \text{ mA}$	V <sub>(BR)</sub>	13	-	V
	TESDE24V			25	-	
	TESDE5V0	$V_R = 5 V$				
Reverse Leakage Current	TESDE12V	$V_R = 12 V$	I <sub>R</sub>	-	2	μA
	TESDE24V	$V_R = 24 V$				
	TESDE5V0	I <sub>PP</sub> = 1 A	V <sub>c</sub>	-	9.8	v
Clamping Voltage		$I_{PP} = 5 A$		-	15	v
	TESDE12V	I <sub>PP</sub> = 1 A	V <sub>c</sub>	-	25	v
Clamping Voltage		$I_{PP} = 5 A$		-	33	v
	TESDE24V	I <sub>PP</sub> = 1 A	V <sub>c</sub>	-	47	- V
Clamping Voltage		$I_{PP} = 5 A$		-	51	
	TESDE5V0			15		
Junction Capacitance	TESDE12V	V <sub>R</sub> = 0 V f = 1.0 MHz	CJ	12		pF
	TESDE24V	i = 1.0 Will IZ		10		



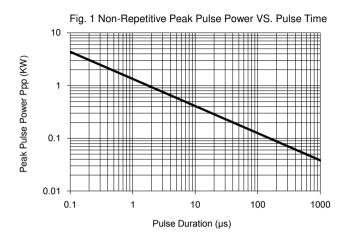
## TESDE5V0/TESDE12V/TESDE24V

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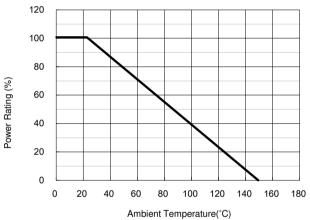
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### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub>=25°C unless otherwise noted)



#### Fig. 3 Admissible Power Dissipation Curve





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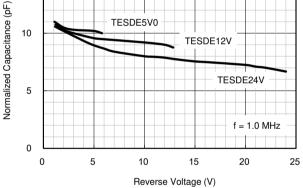
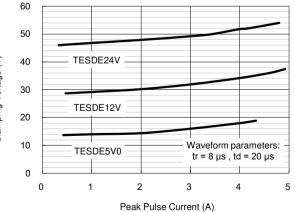
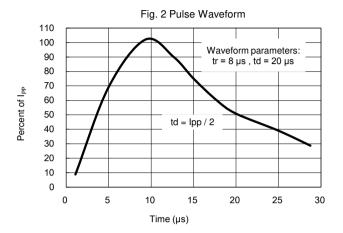


Fig. 4 Typical Junction Capacitance











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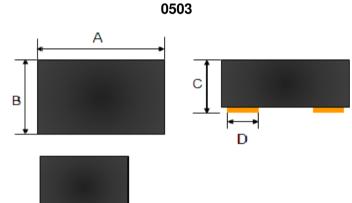
ORDERING INFORMATION				
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
TESDExxx (Note 1, 2)	RG	G	0503	4,000 / 7" reel

Note 1: "xxx" is Device Code from "5V0" - "24V".

Note 2: Whole series with green compound

EXAMPLE				
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
TESDE5V0 RGG	TESDE5V0	RG	G	Green compound

### PACKAGE OUTLINE DIMENSIONS

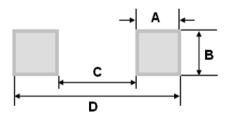


DIM.	Unit (	mm)	Unit (inch)	
DINI.	Min	Мах	Min	Max
А	1.15	1.35	0.045	0.053
В	0.65 0.85		0.026	0.033
С	0.60	0.75	0.024	0.030
D	0.40 (Typ.)		0.016	(Typ.)
E	0.55 (Тур.)		0.022	(Typ.)



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DIM.	Unit (mm)	Unit (inch)
DIM.	Тур.	Тур.
Α	0.55	0.022
В	0.85	0.033
С	0.30	0.012
D	1.40	0.055

Note: The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary depending on application.

#### MARKING

Part NO.	Marking
TESDE5V0	E05
TESDE12V	E12
TESDE24V	E24



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#### **APPLICATION INFROMATION**

- Designed to protect one data, I/O, or power supply line
- Designed to protect sensitive electronics from damage or latch-up due to ESD
- Designed to replace multilayer varistors (MLVs) in portable applications
- Features large cross-sectional area junctions for conducting high transient currents
- Offers superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs
- The combination of small size and high ESD surge capability makes them ideal for use in portable applications

#### **CIRCUIT BOARD LAYOUT RECOMMENDATIONS**

- Good circuit board layout is critical for the suppression of ESD induced transients
- Place the ESD Protection Diode near the input terminals or connectors to restrict transient coupling
- Minimize the path length between the ESD Protection Diode and the protected line
- Minimize all conductive loops including power and ground loops
- The ESD transient return path to ground should be kept as short as possible
- Never run critical signals near board edges
- Use ground planes whenever possible



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# TESDE5V0/TESDE12V/TESDE24V

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